

1SS82

Silicon Epitaxial Planar Diode for High Voltage Switching

REJ03G0562-0300

(Previous: ADE-208-149B)

Rev.3.00 Mar 22, 2005

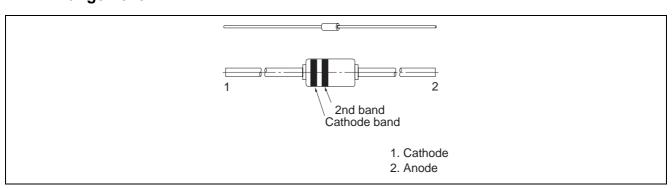
Features

- High reverse voltage. $(V_R = 200 \text{ V})$
- High reliability with glass seal.

Ordering Information

Type No.	Cathode band	2nd band	Package Name	Package Code (Previous Code)
1SS82	Verdure	Light Blue	DO-35	GRZZ0002ZB-A (DO-35)

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Peak reverse voltage	V _{RM} * ¹	250	V
Reverse voltage	V _R	200	V
Average rectified current	I ₀	200	mA
Peak forward current	I _{FM}	625	mA
Non-Repetitive peak forward surge current	I _{FSM} * ²	1	Α
Power dissipation	Pd	400	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	−65 to +175	°C

Notes: 1. Reverse voltage in excess of peak reverse voltage may deteriorate electrical characteristic.

2. Within 1s forward surge current.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _{R1}			200	nA	V _R = 200 V
	I _{R2}			100	μΑ	V _R = 250 V
Forward voltage	V_{F}			1.0	V	I _F = 100 mA
Capacitance	С	_	1.5	_	pF	V _R = 0 V, f = 1 MHz
Reverse recovery time	t _{rr}	_	_	100	ns	$I_F = I_R = 30 \text{ mA}, Irr = 3 \text{ mA}, R_L = 100 \Omega$

Main Characteristic

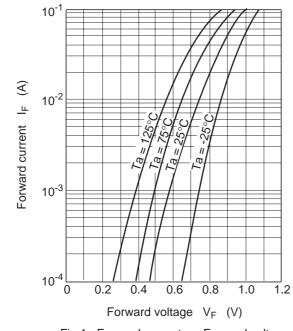


Fig.1 Forward current vs. Forward voltage

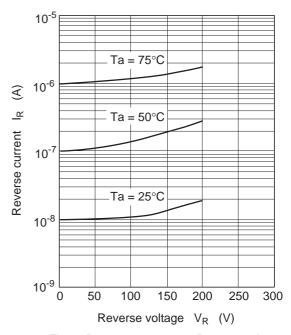
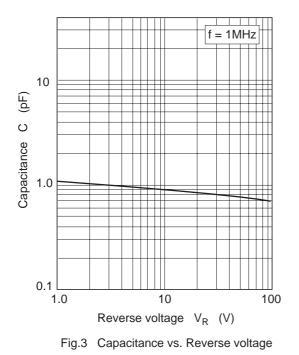
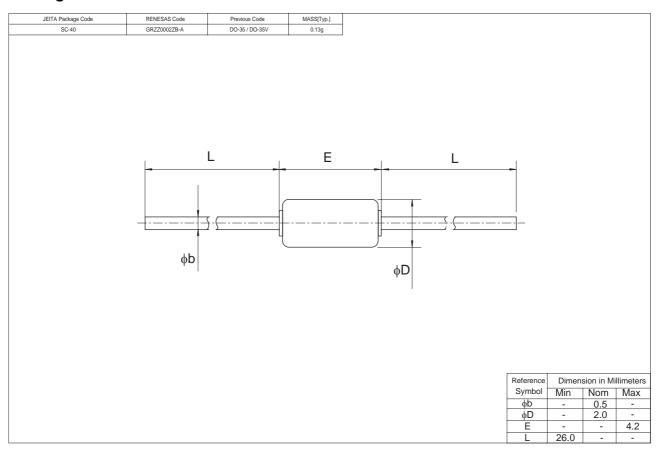


Fig.2 Reverse current vs. Reverse voltage



Package Dimensions



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